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# Impedance Characterization of High Frequency Power Electronic Circuits

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## **Introduction: Half-Bridge at Challenges**



input: ideal voltage source:
output:
output:
storage elements, resonant tanks



- task: <u>higher operating frequency</u> 1 100 MHz
  - capacitively coupled plasma sources (discharge lamps)
- inductively coupled plasma sources (discharge lamps)



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#### Impedance Measurement – Information to be Extracted





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#### **Impedance Measurement Setup with DC-bias**









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## **RF** resonant pulse generator







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#### **Resonant Behaviour Without DC-bias**



#### resonances of freewheeling circuit, both switches off

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## Variance in Switch Output Capacitance





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## **RF-half-bridge Decoupling Performance**





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## Summary



- RF half-bridges:
- ensure low leg inductance
- ensure low source impedance
- Impedance measurement with DC bias:
- DC-blocker built and characterized
- investigates RF circuit performance
- Resonance behaviour of RF half-bridge measured
- Bottleneck detected:

impedance peak due to X7R ceramics



**Question and Answer Part** 



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